International Workshop on Semiconductor Pixel Detectors for Particles and Imaging (PIXEL2012)

Friday, 7 September 2012

Session8 (08:30 - 11:30)

-Conveners: Kazuhisa Yamamura; Yoshinobu Unno

time	[id] title	presenter
08:30	[12] Analysis of Edge and Surface TCTs for Irradiated 3D Silicon Strip Detectors	STEWART, Graeme Douglas
08:50	[76] Recent results on 3D double sided detectors at CNM-IMB	PELLEGRINI, Giulio
09:10	[69] Future trends of 3D silicon sensors	Dr DA VIA, Cinzia
09:30	[72] Results of a Multi Project Wafer Process of Edgeless Silicon Pixel Detectors	Dr KALLIOPUSKA, Juha
09:50	[51] Thin n-in-p pixel sensors and the SLID-ICV vertical integration technology for the ATLAS upgrade at HL-LHC	MACCHIOLO, Anna
10:10	Coffee break	
10:30	[94] Radiation hardness and slim edge studies of planar n-in-n ATLAS pixel sensors for HL-LHC upgrades	WITTIG, Tobias
10:50	[77] Results with p-type pixel sensors with different geometries for the HL-LHC	DERVAN, Paul
11:10	[95] Planar pixel detector module development for the HL-LHC ATLAS pixel system	BATES, Richard